



DMN52D0UDM

Product Summary

BV _{DSS}	Rds(on) Max	I _D T _A = +25°C
	$2\Omega @ V_{GS} = 5V$	410mA
50V	2.5Ω @ V _{GS} = 2.5V	370mA
	4Ω @ V _{GS} = 1.8V	290mA

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Load switches
- Level switches

50V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: SOT26
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.015 grams (Approximate)



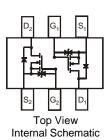


Top View

SOT26

R

Bottom View



Ordering Information (Note 4)

Part Number	Deskare	Packing		
Part Number	Package	Qty.	Carrier	
DMN52D0UDM-7	SOT26	3000	Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

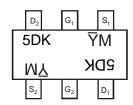
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



 $\underline{5}DK = Product Type Marking Code$ $\overline{Y}M = Date Code Marking$ \overline{Y} = Year (ex: K = 2023) M = Month (ex: 6 = June)

Balo Codo Hoy												
Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	К	L	М	N	Р	R	S	Т	U	V	W	Х
-	1							-	-	- ·		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	50	V		
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 6) V _{GS} = 5V	Steady State	ID	410 260	mA	
Maximum Continuous Body Diode Forward Curr	ls	410	mA		
Pulsed Drain Current (10µs Pulse, Duty Cycle =	IDM	1.2	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.49	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	256	°C/W
Total Power Dissipation (Note 6)		PD	0.74	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	170	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



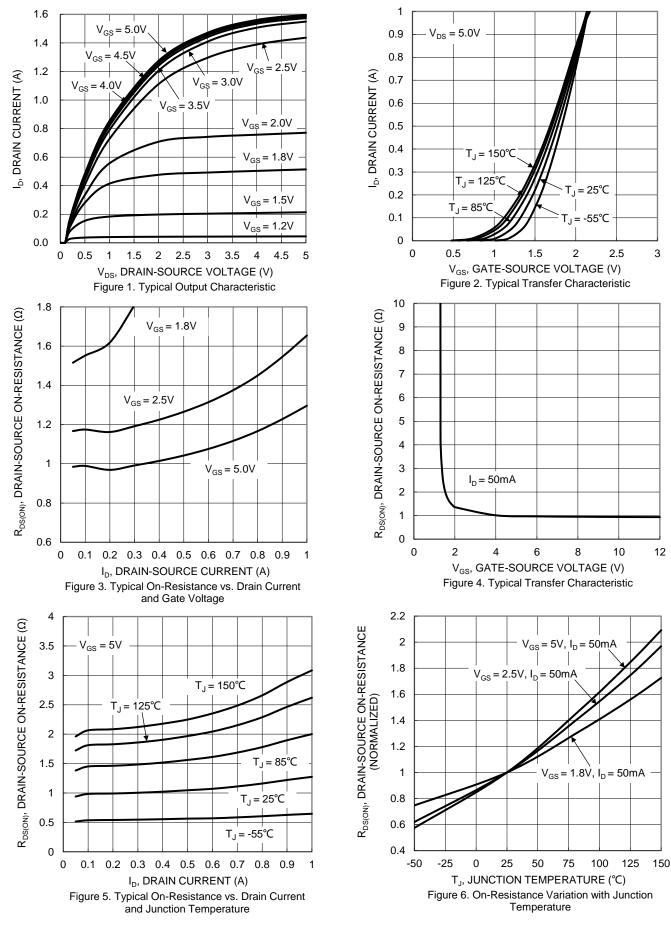
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	Тур	WIdX	Unit	Test Condition
Drain-Source Breakdown Voltage	BVpss	50	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_		1	μA	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	000					
Gate Threshold Voltage	Vgs(th)	0.49		1.0	V	V _{DS} = V _{GS} , I _D = 250µA
		_	1.5	4.0		V _{GS} = 1.8V, I _D = 50mA
Static Drain-Source On-Resistance	RDS(ON)	_	1.2	2.5	Ω	V _{GS} = 2.5V, I _D = 50mA
		_	0.95	2.0		V _{GS} = 5.0V, I _D = 50mA
Diode Forward Voltage	Vsd	_	0.6	1.2	V	$V_{GS} = 0V, I_D = 50mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	42.4	_	pF	
Output Capacitance	Coss	_	6.1	—	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.8	_	pF	
Gate Resistance	Rg	_	51.8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	0.9	—	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	1.6	—	nC nC	$V_{DS} = 25V, I_D = 50mA$
Gate-Source Charge	Q _{gs}	_	0.2	—		
Gate-Drain Charge	Q _{gd}	_	0.2	—	nC	7
Turn-On Delay Time	tD(ON)		1.3	—	ns	
Turn-On Rise Time	tR	_	9.5	_	ns	$V_{DS} = 25V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	—	32	—	ns	$R_G = 50\Omega$, $I_D = 50mA$
Turn-Off Fall Time	t⊧	—	37.5	_	ns	

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.



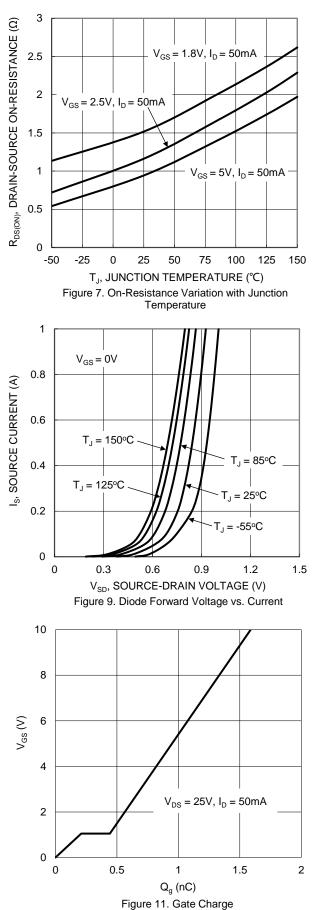
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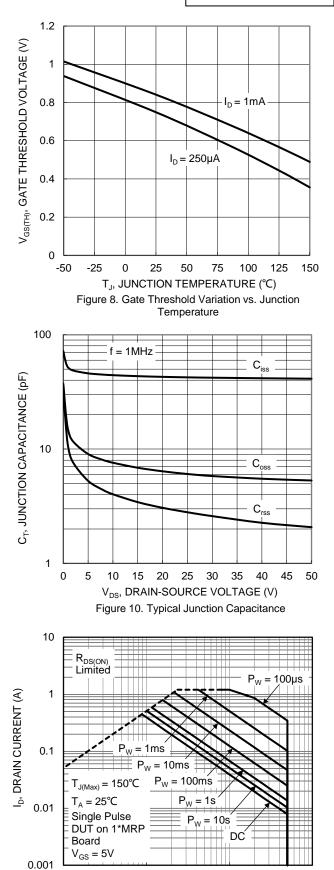


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V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area

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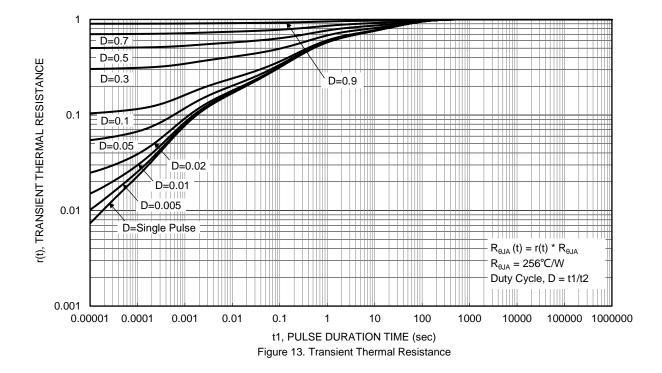
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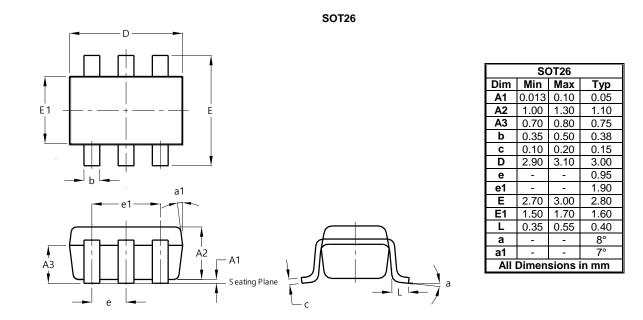






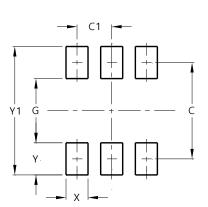
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20

SOT26



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